<u>TOSHIBA</u>

TOSHIBA Transistor Silicon NPN Triple Diffused Type (PCT Process)

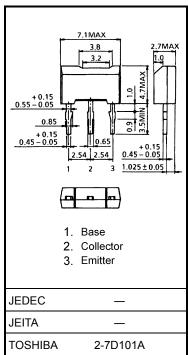
2SC5930

High-Speed and High-Voltage Switching Applications Switching Regulator Applications DC-DC Converter Applications

• High-speed switching: $t_f = 0.3 \ \mu s \ (max) \ (I_C = 0.3 \ A)$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	600	V	
Collector-emitter voltage		V _{CEX}	600	V	
Collector-emitter voltage		V _{CEO}	285	V	
Emitter-base voltage		V _{EBO}	7	V	
Collector current	DC	Ι _C	1.0	A	
	Pulse	ICP	2.0		
Base current		Ι _Β	0.5	А	
Collector power dissipation	Ta = 25°C	P _C	1.0	W	
Junction temperature		Тj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 0.2 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high

temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating

temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Unit: mm

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	$V_{CB} = 600 V, I_E = 0$	—	_	100	μA
Emitter cut-off current		I _{EBO}	$V_{EB}=7~V,~I_C=0$	_		100	μA
Collector-base breakdown voltage		V (BR) CBO	$I_C=1\ mA,\ I_B=0$	600		_	V
Collector-emitter breakdown voltage		V (BR) CEO	$I_C=10\ mA,\ I_B=0$	285		_	V
DC current gain		h _{FE} (1)	$V_{CE} = 5 \text{ V}, \text{ I}_{C} = 1 \text{ mA}$	30		100	
		h _{FE} (2)	$V_{CE} = 5 \text{ V}, \ I_C = 0.2 \text{ A}$	40	_	100	
Collector-emitter sat	turation voltage	V _{CE (sat)}	$I_C = 0.6 \text{ A}, I_B = 0.075 \text{ A}$	_		1.0	V
Base-emitter saturation voltage		V _{BE (sat)}	$I_C = 0.6 \text{ A}, \ I_B = 0.075 \text{ A}$	_	_	1.3	V
Switching time	Rise time	tr	See Figure 1. V _{CC} ≈ 200 V, R _L = 667 Ω I _{B1} = 20 mA, $-I_{B2}$ = 50 mA	_		0.5	
	Storage time	t _{stg}		_		3.0	μS
	Fall time	t _f				0.3	

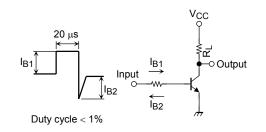
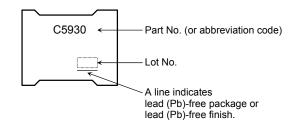
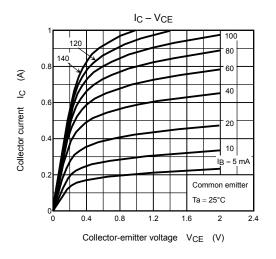


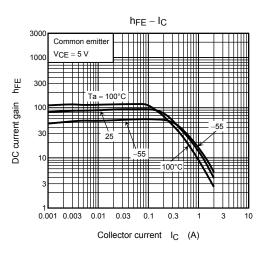
Figure 1 Switching Time Test Circuit & Timing Chart

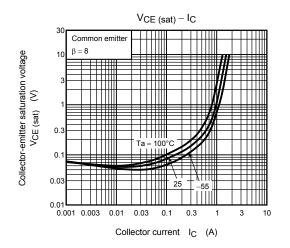
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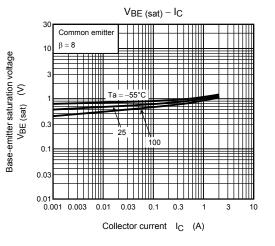


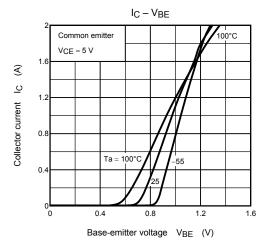
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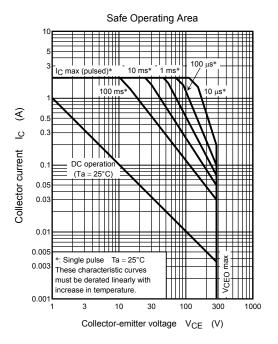








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